# μESD3.3ST5G SERIES

## **Product Preview**

## **ESD Protection Diodes**

## In Ultra Small SOD-723 Package

The µESD Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

### **Specification Features:**

• Small Body Outline Dimensions: 0.055" x 0.024" (1.40 mm x 0.60 mm)

Low Body Height: 0.020" (0.5 mm)
Stand-off Voltage: 3.3 V - 12 V

• Low Leakage

• Response Time is Typically < 1 ns

• ESD Rating of Class 3 (> 16 kV) per Human Body Model

• IEC61000–4–2 Level 4 ESD Protection

• IEC61000-4-4 Level 4 EFT Protection

• These are Pb-Free Devices

### Mechanical Characteristics:

**CASE:** Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

**LEAD FINISH:** 100% Matte Sn (Tin)

**MOUNTING POSITION:** Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
IEC 61000–4–2 (ESD) Air Contact		±30 ±30	kV
IEC 61000-4-4 (EFT)		40	Α
ESD Voltage Per Human Body Model Per Machine Model		16 400	kV V
Total Power Dissipation on FR–5 Board (Note 1) @ T <sub>A</sub> = 25°C	P <sub>D</sub>	150	mW
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	ozšc.	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1.  $FR-5 = 1.0 \times 0.75 \times 0.62$  in.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.



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PIN 1. CATHODE 2. ANODE



SOD-723 CASE 509AA



LO M

L0 = Specific Device Code
M = Date Code

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>		
μESDxxST5G	SOD-723	8000/Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **DEVICE MARKING INFORMATION**

See specific marking information in the device marking column of the table on page 2 of this data sheet.

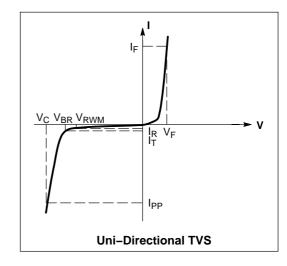
E E WWW.DZSG.COM

## $\mu \text{ESD3.3ST5G SERIES}$

### **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
$V_{RWM}$	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
$V_{BR}$	Breakdown Voltage @ I <sub>T</sub>
Ι <sub>Τ</sub>	Test Current
I <sub>F</sub>	Forward Current
$V_{F}$	Forward Voltage @ I <sub>F</sub>
$P_{pk}$	Peak Power Dissipation
С	Max. Capacitance @V <sub>R</sub> = 0 and f = 1 MHz



## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{A} = 25^{\circ}C \ unless \ otherwise \ noted, \ V_{F} = 0.9 \ V \ Max. \ @ \ I_{F} = 10 \ mA \ for \ all \ types)$

	Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (μΑ) @ V <sub>RWM</sub>	V <sub>BR</sub> (V) @ I <sub>T</sub> (Note 2)	Ι <sub>Τ</sub>	C (pF)
Device*	Marking	Max	Max	Min	mA	Тур
μESD3.3ST5G	TBD	3.3	2.5	5.0	1.0	90
μESD5.0ST5G	TBD	5.0	1.0	6.2	1.0	65
μESD12ST5G	TBD	12	1.0	13.5	1.0	55

<sup>\*</sup>Other voltages available upon request. 2.  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C.

## μESD3.3ST5G SERIES

### **TYPICAL CHARACTERISTICS**

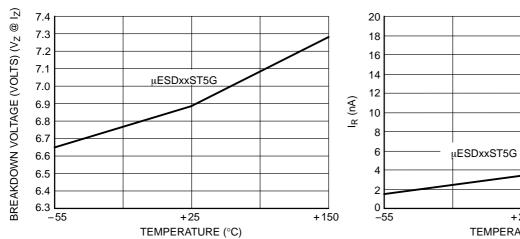


Figure 1. Typical Breakdown Voltage versus Temperature

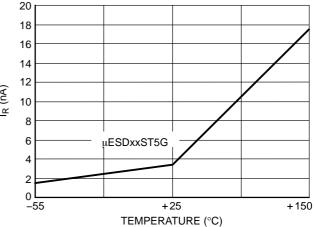
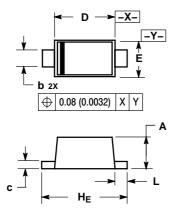


Figure 2. Typical Leakage Current versus Temperature

### μESD3.3ST5G SERIES

#### PACKAGE DIMENSIONS

SOD-723 CASE 509AA-01 ISSUE O

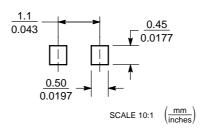


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   VIA EM 1082
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
   MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MIL	LIMETE	RS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.49	0.52	0.55	0.019	0.020	0.022
b	0.25	0.28	0.32	0.0098	0.011	0.013
С	0.08	0.12	0.15	0.0032	0.0047	0.0059
D	0.95	1.00	1.05	0.037	0.039	0.041
Е	0.55	0.60	0.65	0.022	0.024	0.026
HE	1.35	1.40	1.45	0.053	0.055	0.057
L	0.15	0.20	0.25	0.006	0.0079	0.010

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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